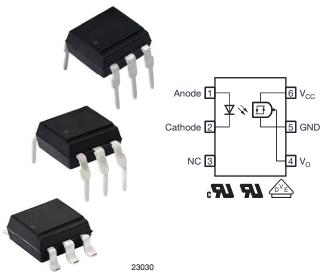
Vishay Semiconductors

High Speed Optocoupler, 1 MBd, Schmitt Trigger



DESIGN SUPPORT TOOLS









DESCRIPTION

The VOH1016A is a single channel 1 MBd optocoupler utilizing a high efficient input LED coupled with an integrated optical photodiode IC detector. The detector has an open collector transistor output with Schmitt-Trigger functionality. The low turn-on threshold and low supply current together with a guaranteed common mode transient immunity of 10 kV/µs makes the VOH1016A to a perfect solution for galvanic noise isolation or to break up ground loops in digital applications. The wide power supply range up to 15 V enables isolated level shifting in applications using different voltage domains.

FEATURES

- High data rate 2 MHz (NRZ)
- Latch up and oscillation free
- Low turn-on threshold current 2 mA
- Logic compatible output
- · Guaranteed on / off threshold hysteresis
- Wide supply voltage range 3 V to 15 V
- Minimum common mode transient immunity (CMTI) 10 kV/µs
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

APPLICATIONS

- Microprocessor system interface
- Ground loop elimination
- · Galvanic noise isolation
- Serial bus systems
- · Digital control power supply
- · Signal level translation
- PLC, ATE input / output isolation
- · Computer peripheral interface

AGENCY APPROVALS

- <u>UL 1577</u>
- cUL 1577
- DIN EN 60747-5-5 (VDE 0884-5) available with option "V"

ORDERING INFORMATION				
V O H 1 0 1 6 A # - V T #				
PART NUMBER	PACKAGE VDE TAPE OPTION OPTION AND REEL			
AGENCY CERTIFIED / PACKAGE	CMTI (kV/µs)			
UL, cUL	10			
DIP-6	VOH1016AD			
DIP-6, 400 mil	VOH1016AG			
SMD-6	VOH1016AB-T			
SMD-6, 180° oriented	VOH1016AB-T2			
VDE, UL, cUL	10			
DIP-6	VOH1016AD-V			
DIP-6, 400 mil	VOH1016AG-V			
SMD-6	VOH1016AB-VT			
SMD-6, 180° oriented	VOH1016AB-VT2			

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TRUTH TABLE (positive logic)			
LED OUTPUT			
On	L		
Off	Н		

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	CONDITIONS	SYMBOL	VALUE	UNIT		
INPUT						
Forward current		I _F	50	mA		
Reverse voltage		V _R	6	V		
Power dissipation		P _{diss}	120	mW		
OUTPUT	OUTPUT					
Supply voltage		V _{CC}	16	V		
Output voltage		Vo	V _{CC}	V		
Output current		I _O	50	mA		
Power dissipation		P _{diss}	130	mW		
COUPLER						
Power dissipation		P _{diss}	250	mW		
Storage temperature		T _{stg}	-55 to +150	°C		
Operating temperature		T _{amb}	-40 to +100	°C		
Solder temperature	For 10 s	T _{sld}	260	°C		

Note

• Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability

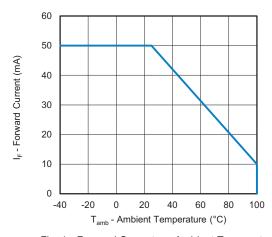


Fig. 1 - Forward Current vs. Ambient Temperature

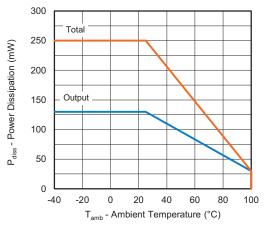


Fig. 2 - Power Dissipation vs. Ambient Temperature

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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION		MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	I _F = 4 mA	V _F	-	1.1	1.4	V
i diward voitage	$I_F = 0.3 \text{ mA}$	VF	0.7	1.0	-	V
Reverse current	V _R = 3 V	I _R	-	-	10	μΑ
Input capacitance	$f = 1 MHz, V_F = 0 V$	C _{IN}	-	30	250	pF
OUTPUT	OUTPUT					
Supply voltage		V _{CC}	3	-	15	>
High level supply current	$I_F = 0$ mA, $V_{CC} = 5$ V	I _{CCH}	-	0.55	1.0	mA
Low level supply current	$I_F = 4 \text{ mA}, V_{CC} = 5 \text{ V}$	I _{CCL}	-	0.55	1.0	mA
High level output current	$V_{CC} = V_{O} = 15 \text{ V}, I_{F} = 0 \text{ mA}$	I _{OH}	-	-	100	μΑ
Low level output voltage	$V_{CC} = 5 \text{ V}, I_F = 4 \text{ mA}, I_{OL} = 16 \text{ mA}$	V_{OL}	-	0.2	0.4	V
Turn-On threshold current	V_{CC} = 5 V, R_L = 280 Ω	I _{F(on)}	-	0.65	2.0	mA
Turn-Off threshold current	$V_{CC} = 5 \text{ V}, R_L = 280 \Omega$	I _{F(off)}	0.4	0.6	-	mA
Hysteresis ratio	$V_{CC} = 5 \text{ V}, R_L = 280 \Omega$	$I_{F(off)}/I_{F(on)}$	0.5	0.9	0.95	

Note

 Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Propagation delay time to high output level	$R_L = 280 \ \Omega, \ V_{CC} = 5 \ V,$ $I_F = 4 \ mA$	t _{PLH}	-	0.25	2	μs
Propagation delay time to low output level		t _{PHL}	-	0.05	1.2	μs
Rise time		t _r	-	0.05	0.5	μs
Fall time		t _f	-	0.04	0.5	μs
Data rate			-	2	-	MHz

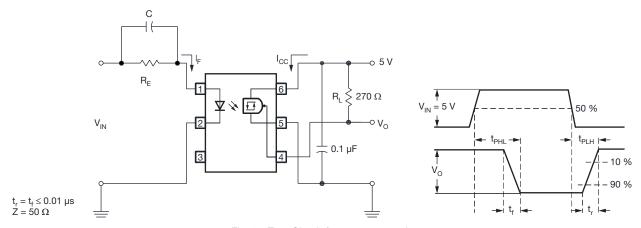


Fig. 3 - Test Circuit for $t_{\text{on}},\,t_{\text{off}},\,t_{\text{r}},\,\text{and}\,\,t_{\text{f}}$

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COMMON MODE TRANSIENT IMMUNITY (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER TEST CONDITION SYMBOL MIN. TYP. MAX.					UNIT	
Common mode transient immunity	$R_L = 270~\Omega,~V_{CC} = 5~V,~V_{CM} = 1000~V,\\ I_F = 0~mA$	CM _H	10	-	-	kV/μs
Common mode transient immunity	$R_L = 270 \Omega$, $V_{CC} = 5 V$, $V_{CM} = 1000 V$, $I_F = I_{F(on)}$ (max.)	CM _L	10	-	-	kV/μs

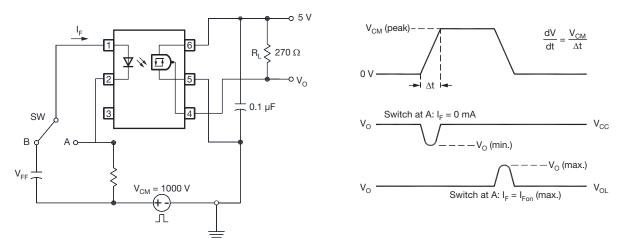


Fig. 4 - Test Circuit for Common Mode Transient Immunity

SAFETY AND INSULATION RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Comparative tracking index	Insulation group IIIa	CTI	175			
Maximum rated withstanding isolation voltage	According to UL1577, t = 1 min	V _{ISO}	5000	V_{RMS}		
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V _{IOTM}	6000	V _{peak}		
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V _{IORM}	630	V _{peak}		
Landa Cara and Salara and	$T_{amb} = 25 ^{\circ}C, V_{IO} = 500 V$	R _{IO}	10 ¹²	Ω		
Isolation resistance	T _{amb} = 100 °C, V _{IO} = 500 V	R _{IO}	10 ¹¹	Ω		
Output safety power		P _{SO}	150	mW		
Input safety current		I _{SI}	20	mA		
Input safety temperature		T _S	175	°C		
Creepage distance			> 7	mm		
Clearance distance			> 7	mm		
Insulation thickness		DTI	> 0.4	mm		

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

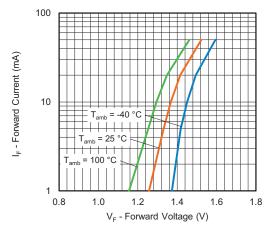


Fig. 5 - Forward Current vs. Forward Voltage

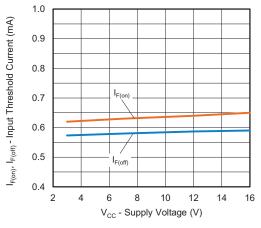


Fig. 6 - Input Threshold Current vs. Supply Voltage

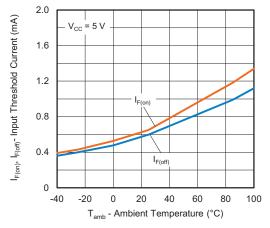


Fig. 7 - Input Threshold Current vs. Ambient Temperature

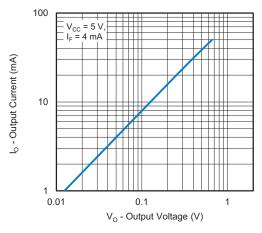


Fig. 8 - Output Current vs. Output Voltage

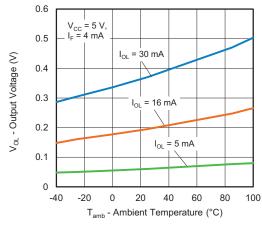


Fig. 9 - Output Voltage vs. Ambient Temperature

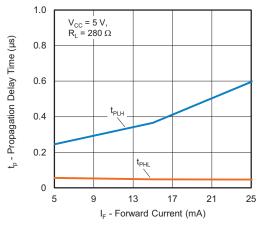


Fig. 10 - Propagation Delay Time vs. Forward Current

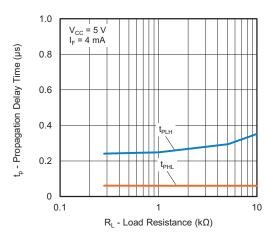


Fig. 11 - Propagation Delay Time vs. Load Resistance

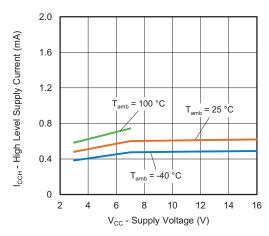


Fig. 12 - High Level Supply Current vs. Supply Voltage

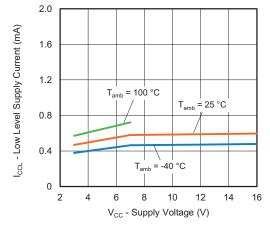
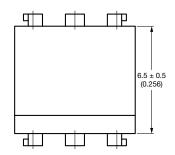
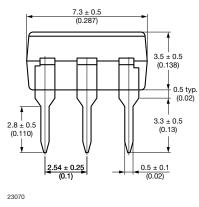


Fig. 13 - Low Level Supply Current vs. Supply Voltage

PACKAGE DIMENSIONS (in millimeters)

DIP-6





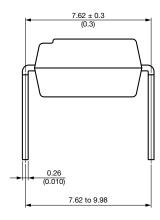
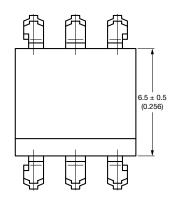
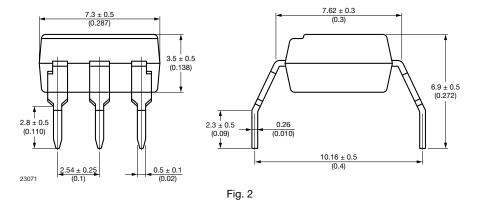


Fig. 1

DIP-6, 400 mil

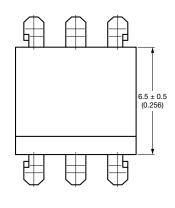


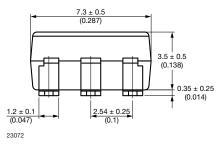


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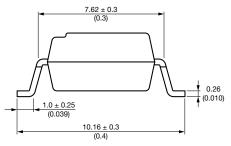


Fig. 3

PACKAGE MARKING



Fig. 14 - Example of VOH1016AB-VT

Notes

- "YWW" is the date code marking (Y = year code, WW = week code)
- VDE logo is only marked on option "V" parts
- Tape and reel suffix (T) is not part of the package marking

PACKING INFORMATION (in millimeters)

DEVICES PER TUBES				
TYPE	UNITS/TUBE	TUBES/BOX	UNITS/BOX	
DIP-6	50	40	2000	
DIP-6, 400 mil	50	40	2000	

Tape SMD-6

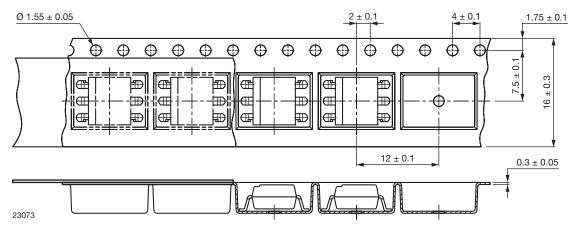


Fig. 15 - Tape and Reel Packaging (1000 pieces on reel)

Tape SMD-6, 180° orientation

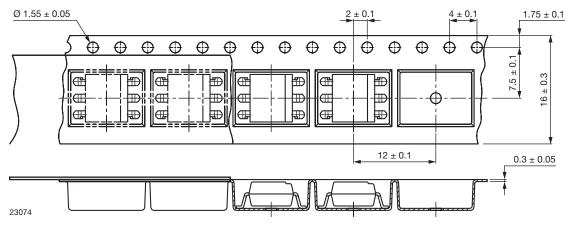


Fig. 16 - Tape and Reel Packaging (1000 pieces on reel)

Reel

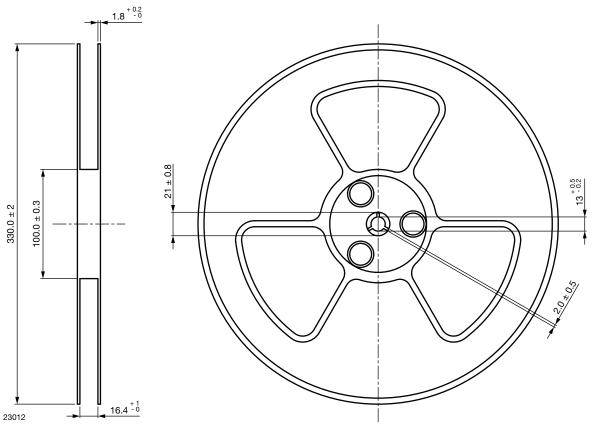


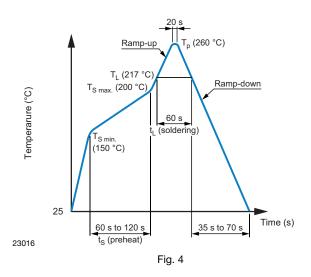
Fig. 17 - Tape and Reel Shipping Medium

SOLDER PROFILES

IR Reflow Soldering (JEDEC® J-STD-020C compliant)

One time soldering reflow is recommended within the condition of temperature and time profile shown below. Do not solder more than three times.

PROFILE ITEM	CONDITIONS
Preheat	
- Temperature minimum (T _{S min.})	150 °C
- Temperature maximum (T _{S max.})	200 °C
- Time (min. to max.) (t _S)	90 s ± 30 s
Soldering zone	
- Temperature (T _L)	217 °C
- Time (t _L)	60 s
Peak temperature (T _p)	260 °C
Ramp-up rate	3 °C/s max.
Ramp-down rate	3 °C/s to 6 °C/s





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Wave Soldering (JEDEC JESD22-A111 compliant)

One time soldering is recommended within the condition of temperature.

Temperature: 260 °C + 0 °C / - 5 °C

Time: 10 s

Preheat temperature: 25 °C to 140 °C

Preheat time: 30 s to 80 s

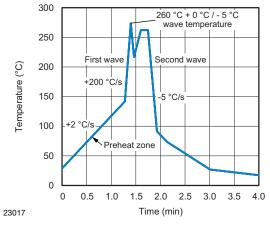


Fig. 5

Hand Soldering by Soldering Iron

Allow single lead soldering in every single process. One time soldering is recommended.

Temperature: 380 °C + 0 °C / - 5 °C

Time: 3 s max.

HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions: T_{amb} < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



Legal Disclaimer Notice

Vishay

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